

1 of 5

Small Signal Fast Switching Diode

General Description

General-purpose switching diodes, fabricated in planar technology, and packaged in small SOT-363 surface mounted device (SMD) packages.

Features and Benefits

- Silicon epitaxial planar diode
- High switching speed: trr≤4ns
- · Low forward drop voltage and low leakage current
- "Green" device and RoHS compliant device
- Available in full lead (Pb)-free device

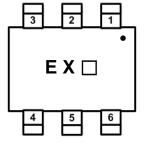
Applications

· Ultra high speed switching application

Ordering Information

Part Number	Marking Code	Package	Packaging
SUD494J	EX 🗆	SOT-363	Tape & Reel

Marking Information



E X = Specific Device Code

□ = Year & Week Code Marking

Pinning Information

Pin	Description	Simplified Outline	Graphic Symbol
1	Cathode (Diode 1)		
2	Cathode (Diode 2)	3 2 1	3 2 1
3	Cathode (Diode 3)	•	
4	Anode (Diode 3)		
5	Anode (Diode 2)	4 5 6	4 5 6
6	Anode (Diode 1)		





SOT-363

SUD494J SWITCHING DIODE

Absolute Maximum Ratings (T_{amb}=25°C, Unless otherwise specified)

Characteristic	Symbol	Ratings	Unit	
Maximum repetitive peak reverse voltage	V _{RM}	85	V	
Continuous reverse voltage	V _R	80	V	
Maximum average forward rectified current	lo	100	mA	
Forward current (DC)	l _F	100	mA	
Maximum repetitive peak forward current	I _{FM}	300	mA	
Non-repetitive peak forward surge current(t=10ms)	I _{FSM}	2	А	
Power dissipation ¹⁾	P _D	150	mW	

¹⁾ Device mounted on FR-4 board with recommended pad layout.

Thermal Characteristics (T_{amb}=25°C, Unless otherwise specified)

Characteristic	Symbol	Ratings	Unit	
Thermal resistance, junction to ambient 1)	R _{th(j-a)}	830	°C/W	
Operating junction temperature	Tj	150	°C	
Storage temperature range	T _{stg}	-55 ~ 150	°C	

¹⁾ Device mounted on FR-4 board with recommended pad layout.

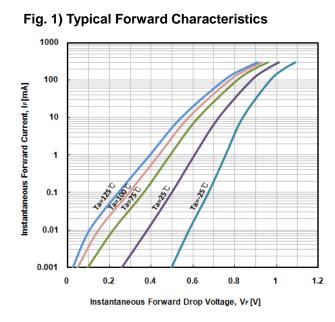
Electrical Characteristics (T_{amb}=25°C, Unless otherwise specified)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Forward voltage ²⁾	V _{F(1)}	I _F =1mA	-	0.6	-	V
	$V_{F(2)}$	I _F =10mA	-	0.7	-	V
	V _{F(3)}	I _F =100mA	-	0.9	1.2	V
Reverse leakage current 3)	I _R	V _R =80V	-	-	0.5	uA
Total capacitance	C _T	V _R =0V, f=1 ^{MHz}	-	2.2	4.0	pF
Reverse recovery time	t _{rr}	I _F =10mA (Fig. 5)	-	1.6	4.0	ns

²⁾ Pulse test: $t_P \leq 380 \mu s$, Duty cycle $\leq 2\%$

 $^{3)}$ Pulse test: $t_{P}{\leq}5\text{ms},$ Duty cycle ${\leq}2\%$

Rating and Characteristic Curves



100 Ta=125°C 1 0.01 0.0001 Ta=25°C 0.001

40

Fig. 4) Reverse Recovery Time vs. Forward Current

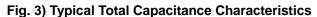
Instantaneous Reverse Voltage, $V_R[V]$

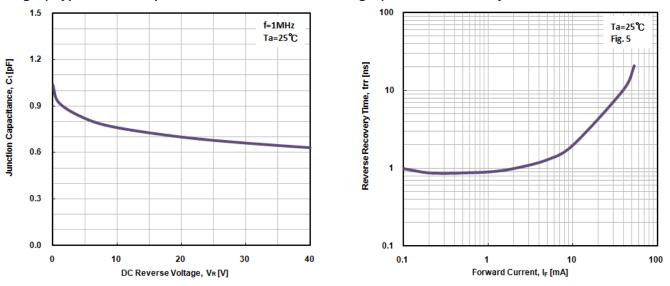
60

80

100

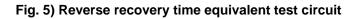
Fig. 2) Typical Reverse Characteristics

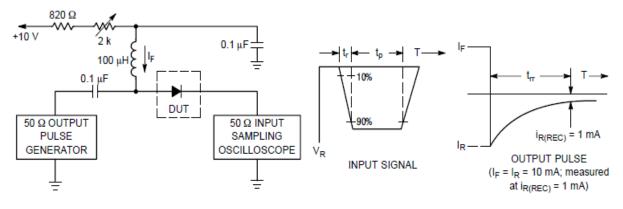




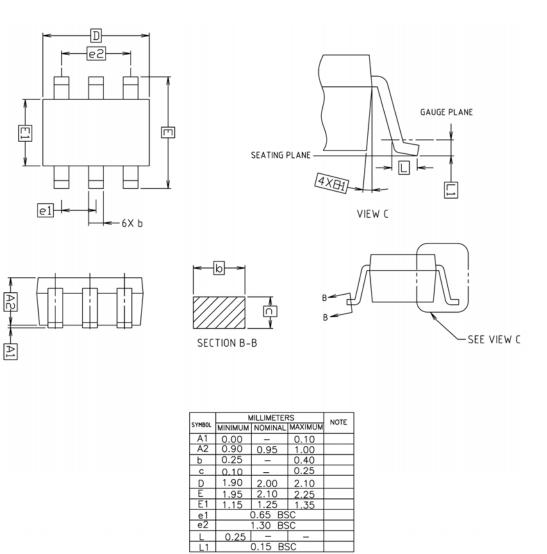
0

20

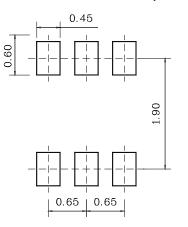




Package Outline Dimensions



※ Recommend PCB solder land (Unit : mm)



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